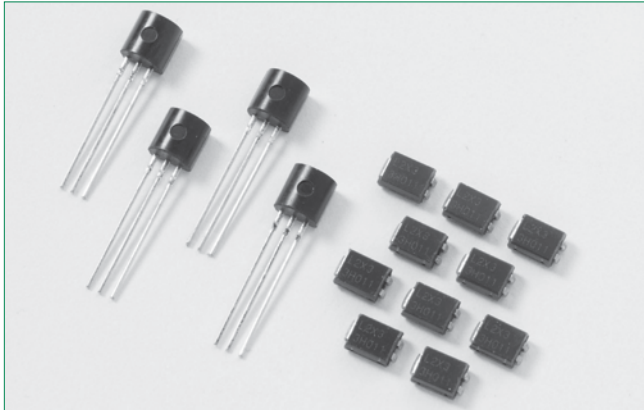


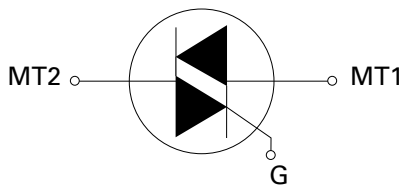
### LxX8Ex & LxXx & QxX8E & QxXx Series



#### Main Features

| Symbol            | Value      | Unit |
|-------------------|------------|------|
| $I_{T(RMS)}$      | 0.8        | A    |
| $V_{DRM}/V_{RRM}$ | 400 to 600 | V    |
| $I_{GT(Q1)}$      | 3 to 25    | mA   |

#### Schematic Symbol



#### Description

0.8 Amp bi-directional solid state switch series is designed for AC switching and phase control applications such as motor speed and temperature modulation controls, lighting controls, and static switching relays.

**Sensitive** type devices guarantee gate control in Quadrants I & IV needed for digital control circuitry.

**Standard** type devices normally operate in Quadrants I & III triggered from AC line.

#### Features

- RoHS Compliant
- Glass – passivated junctions
- Voltage capability up to 600 V
- Surge capability up to 10 A

#### Applications

Excellent for lower current heating controls, water valves, and solenoids.

Typical applications are AC solid-state switches, home/ brown goods and white goods appliances.

Sensitive gate Triacs can be directly driven by microprocessor or popular opto-couplers/isolators.

#### Additional Information


[Datasheet](#)

[Resources](#)

[Samples](#)

#### Absolute Maximum Ratings — Sensitive Triacs (4 Quadrants)

| Symbol       | Parameter  | Value  | Unit                           |
|--------------|--|--|--------------------------------|
| $I_{T(RMS)}$ | RMS on-state current (full sine wave)  | LxX8y/LxXy<br>$T_c = 50^\circ\text{C}$                     | 0.8<br>A                       |
| $I_{TSM}$    | Non repetitive surge peak on-state current (full cycle, $T_j$ initial = $25^\circ\text{C}$ )                   | $f = 50\text{ Hz}$<br>$t = 20\text{ ms}$                   | 8.3<br>A                       |
|              |  | $f = 60\text{ Hz}$<br>$t = 16.7\text{ ms}$                 | 10<br>A                        |
| $I^2t$       | $I^2t$ Value for fusing  | $t_p = 8.3\text{ ms}$                                      | 0.41<br>$\text{A}^2\text{s}$   |
| $di/dt$      | Critical rate of rise of on-state current ( $I_o = 50\text{ mA}$ with $\leq 0.1\text{ }\mu\text{s}$ rise time) | $f = 120\text{ Hz}$<br>$T_j = 110^\circ\text{C}$           | 20<br>$\text{A}/\mu\text{s}$   |
| $I_{GTM}$    | Peak gate trigger current  | $t_p = 10\text{ }\mu\text{s}$<br>$T_j = 110^\circ\text{C}$ | 1<br>A                         |
| $P_{G(AV)}$  | Average gate power dissipation   | $T_j = 110^\circ\text{C}$                                  | 0.2<br>W                       |
| $T_{stg}$    | Storage temperature range  | LxX8Ey   | -65 to 150<br>$^\circ\text{C}$ |
|              |  | LxXy   | -40 to 150<br>$^\circ\text{C}$ |
| $T_j$        | Operating junction temperature range   | LxX8Ey   | -65 to 110<br>$^\circ\text{C}$ |
|              |  | LxXy   | -40 to 110<br>$^\circ\text{C}$ |

Note: x = voltage, y = sensitivity

### Absolute Maximum Ratings — Standard Triac

| Symbol       | Parameter  | Value   | Unit                           |
|--------------|--|---|--------------------------------|
| $I_{T(RMS)}$ | RMS on-state current (full sine wave)  | QxXE8y/<br>QxXy<br>$T_C = 60^\circ\text{C}$                                   | 0.8<br>A                       |
| $I_{TSM}$    | Non repetitive surge peak on-state current (full cycle, $T_J$ initial = $25^\circ\text{C}$ )           | f = 50 Hz<br>t = 20 ms  | 8.3<br>A                       |
|              |  | f = 60 Hz<br>t = 16.7 ms  | 10<br>A                        |
| $I^2t$       | $I^2t$ Value for fusing  | $t_p = 8.3$ ms  | 0.41<br>$\text{A}^2\text{s}$   |
| di/dt        | Critical rate of rise of on-state current ( $I_G = 200\text{mA}$ with $\leq 0.1\mu\text{s}$ rise time) | f = 120 Hz<br>$T_J = 125^\circ\text{C}$                                       | 20<br>$\text{A}/\mu\text{s}$   |
| $I_{GTM}$    | Peak gate trigger current  | $t_p = 10 \mu\text{s};$<br>$I_{GT} \leq I_{GTM}$<br>$T_J = 125^\circ\text{C}$ | 1<br>A                         |
| $P_{G(AV)}$  | Average gate power dissipation   | $T_J = 125^\circ\text{C}$   | 0.2<br>W                       |
| $T_{stg}$    | Storage junction temperature range   | QxX8Ey  | -65 to 150<br>$^\circ\text{C}$ |
|              |  | QxXy  | -40 to 150<br>$^\circ\text{C}$ |
| $T_J$        | Operating junction temperature range   | QxX8Ey  | -65 to 125<br>$^\circ\text{C}$ |
|              |  | QxXy  | -40 to 125<br>$^\circ\text{C}$ |

Note: x = voltage, y = sensitivity

### Electrical Characteristics ( $T_J = 25^\circ\text{C}$ , unless otherwise specified) — Sensitive Triac (4 Quadrants)

| Symbol   | Test Conditions   | Quadrant     | LxX8E3<br>LxX3 | LxX8E5<br>LxX5 | LxX8E6<br>LxX6 | LxX8E8<br>LxX8 | Unit                   |
|----------|---|--------------|----------------|----------------|----------------|----------------|------------------------|
| $I_{GT}$ | $V_D = 12\text{V}$ $R_L = 30 \Omega$                                    | I – II – III | 3              | 5              | 5              | 10             | mA                     |
|          |   | IV           | 3              | 5              | 10             | 20             |                        |
| $V_{GT}$ | $V_D = 12\text{V}$ $R_L = 30 \Omega$                                    | ALL          | 1.3            |                |                |                | V                      |
| $V_{GD}$ | $V_D = V_{DRM}$ $R_L = 3.3 \text{k}\Omega$ $T_J = 110^\circ\text{C}$    | ALL          | 0.2            |                |                |                | V                      |
| $I_H$    | $I_T = 100\text{mA}$  | MAX.         | 5              | 10             | 10             | 15             | mA                     |
| dv/dt    | $V_D = V_{DRM}$ Gate Open $T_J = 100^\circ\text{C}$                     | 400V         | 15             | 15             | 25             | 30             | $\text{V}/\mu\text{s}$ |
|          |   | 600V         | 10             | 10             | 20             | 25             |                        |
| (dv/dt)c | (di/dt)c = 0.43 A/ms $T_J = 110^\circ\text{C}$                          | TYP.         | 0.5            | 1              | 1              | 2              | $\text{V}/\mu\text{s}$ |
| $t_{gt}$ | $I_G = 2 \times I_{GT}$ PW = 15 $\mu\text{s}$ $I_T = 1.13 \text{A(pk)}$ | TYP.         | 2.8            | 3.0            | 3.0            | 3.2            | $\mu\text{s}$          |

### Electrical Characteristics ( $T_J = 25^\circ\text{C}$ , unless otherwise specified) — Standard Triac

| Symbol   | Test Conditions   | Quadrant     | QxX8E3<br>QxX3 | QxX8E4<br>QxX4 | Unit                   |
|----------|---|--------------|----------------|----------------|------------------------|
| $I_{GT}$ | $V_D = 12\text{V}$ $R_L = 60 \Omega$                                    | I – II – III | 10             | 25             | mA                     |
|          |   | IV           | 25             | 50             |                        |
| $V_{GT}$ | $V_D = 12\text{V}$ $R_L = 30 \Omega$                                    | I – II – III | 1.3            | 1.3            | V                      |
| $V_{GD}$ | $V_D = V_{DRM}$ $R_L = 3.3 \text{k}\Omega$ $T_J = 125^\circ\text{C}$    | ALL          | 0.2            | 0.2            | V                      |
| $I_H$    | $I_T = 200\text{mA}$  | MAX.         | 15             | 25             | mA                     |
| dv/dt    | $V_D = V_{DRM}$ Gate Open $T_J = 125^\circ\text{C}$                     | 400V         | 25             | 35             | $\text{V}/\mu\text{s}$ |
|          |   | 600V         | 15             | 25             |                        |
| (dv/dt)c | (di/dt)c = 0.43 A/ms $T_J = 125^\circ\text{C}$                          | TYP.         | 1              | 1              | $\text{V}/\mu\text{s}$ |
| $t_{gt}$ | $I_G = 2 \times I_{GT}$ PW = 15 $\mu\text{s}$ $I_T = 1.13 \text{A(pk)}$ | TYP.         | 2.5            | 3.0            | $\mu\text{s}$          |

Note: x = voltage

### Static Characteristics ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)

| Symbol                 | Test Conditions                    |      | Value         | Unit                      |          |     |         |
|------------------------|------------------------------------|------|---------------|---------------------------|----------|-----|---------|
| $V_{TM}$               | $I_{TM} = 1.13A$ $t_p = 380 \mu s$ | MAX. | 1.60          | V                         |          |     |         |
| $I_{DRM}$<br>$I_{RRM}$ | $V_{DRM} = V_{RRM}$                | MAX. | LxX8Ey / LxXy | $T_J = 25^\circ\text{C}$  | 400-600V | 2   | $\mu A$ |
|                        |                                    |      |               | $T_J = 110^\circ\text{C}$ | 400-600V | 0.1 | mA      |
|                        |                                    |      | QxX8Ey / QxXy | $T_J = 25^\circ\text{C}$  | 400-600V | 5   | $\mu A$ |
|                        |                                    |      |               | $T_J = 125^\circ\text{C}$ | 400-600V | 1   | mA      |

### Thermal Resistances

| Symbol            | Parameter             | Value    | Unit |
|-------------------|-----------------------|----------|------|
| $R_{\theta(J-C)}$ | Junction to case (AC) | L/QxX8Ey | 60   |
|                   |                       | L/QxXy   | 60*  |
| $R_{\theta(J-A)}$ | Junction to ambient   | L/QxX8Ey | 135  |

Note: \* = Mounted on 1 cm<sup>2</sup> 1 copper (two-ounce) foil surface

Figure 1: Definition of Quadrants

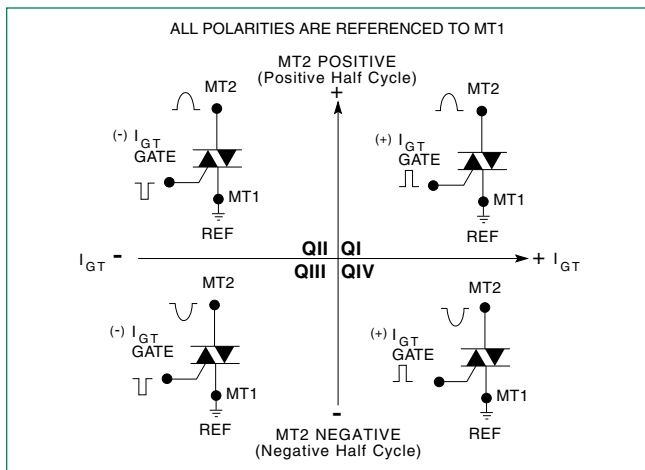
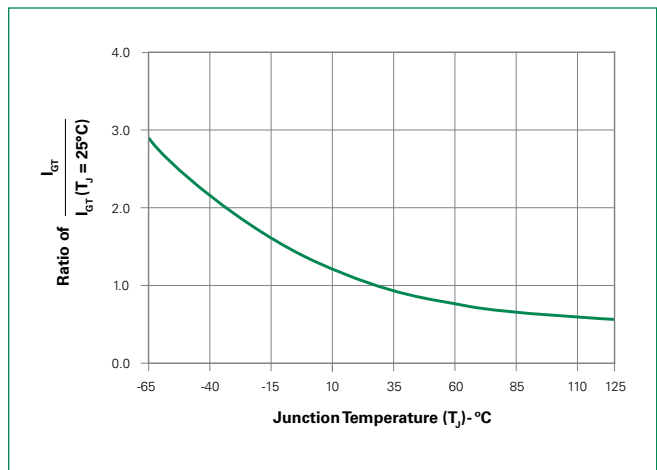
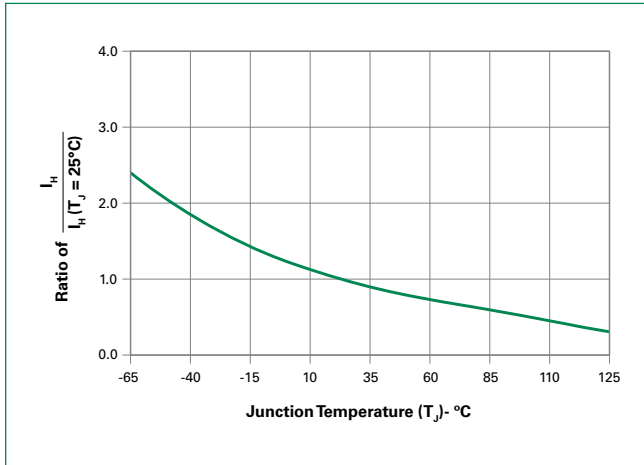


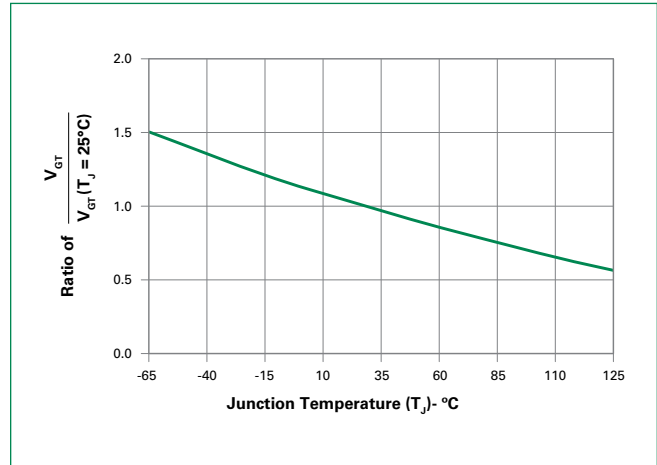
Figure 2: Normalized DC Gate Trigger Current for All Quadrants vs. Junction Temperature



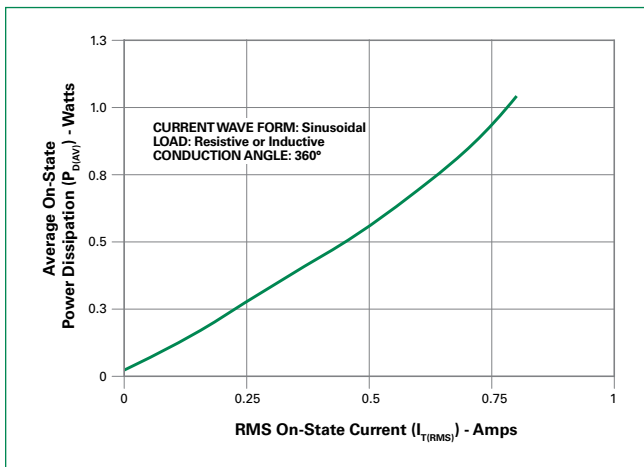
**Figure 3: Normalized DC Holding Current vs. Junction Temperature**



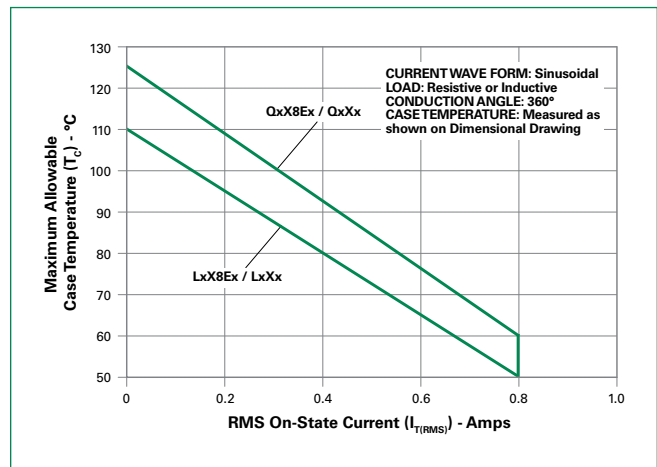
**Figure 4: Normalized DC Gate Trigger Voltage for All Quadrants vs. Junction Temperature**



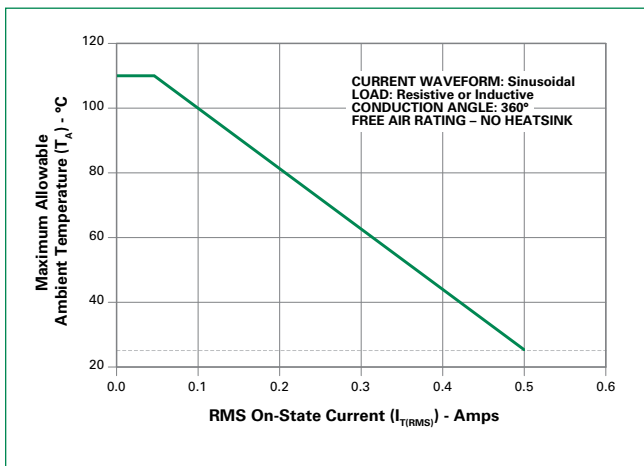
**Figure 5: Power Dissipation (Typical) vs. RMS On-State Current**



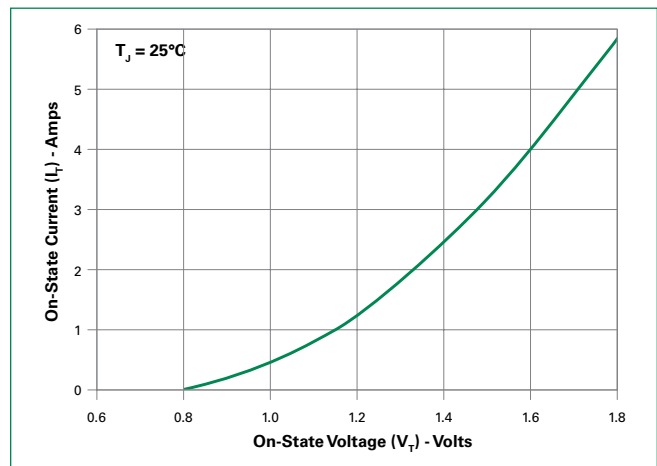
**Figure 6: Maximum Allowable Case Temperature vs. On-State Current**



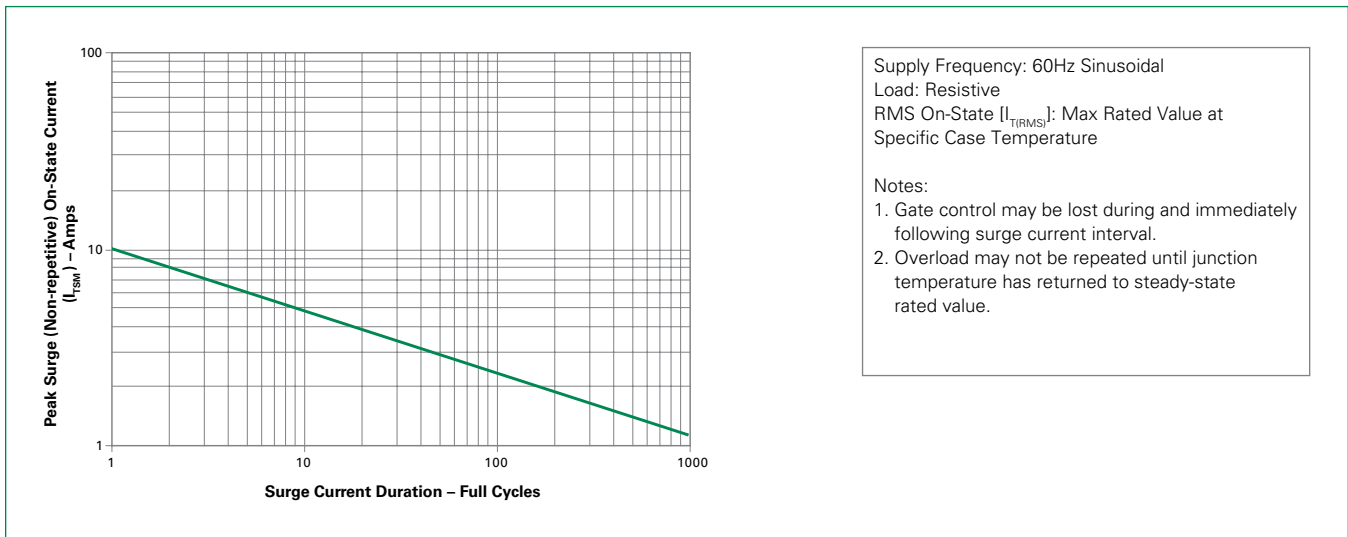
**Figure 7: Maximum Allowable Ambient Temperature vs. On-State Current**



**Figure 8: On-State Current vs. On-State Voltage (Typical)**

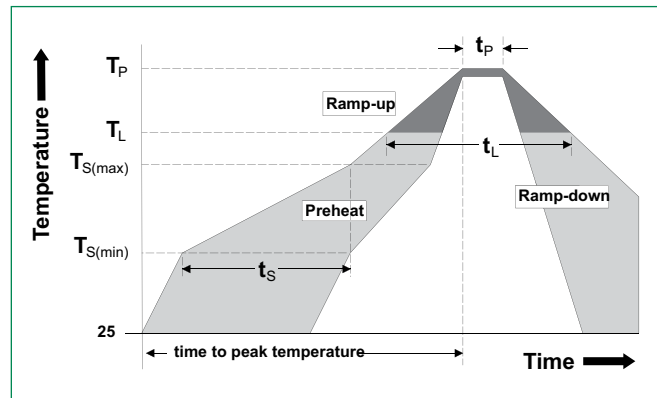


**Figure 9: Surge Peak On-State Current vs. Number of Cycles**



### Soldering Parameters

|  |                                    |                         |
|--|------------------------------------|-------------------------|
| <b>Reflow Condition</b>  |                                    | Pb - Free assembly      |
| <b>Pre Heat</b>  | - Temperature Min ( $T_{s(min)}$ ) | 150°C                   |
|  | - Temperature Max ( $T_{s(max)}$ ) | 200°C                   |
|  | - Time (min to max) ( $t_s$ )      | 60 - 180 secs           |
| <b>Average ramp up rate (Liquidus Temp) (<math>T_L</math>) to peak</b> |                                    | 5°C/second max          |
| <b><math>T_{s(max)}</math> to <math>T_L</math> - Ramp-up Rate</b>      |                                    | 5°C/second max          |
| <b>Reflow</b>  | - Temperature ( $T_L$ ) (Liquidus) | 217°C                   |
|  | - Temperature ( $t_L$ )            | 60 - 150 seconds        |
| <b>Peak Temperature (<math>T_p</math>)</b>                             |                                    | 260 <sup>+0/-5</sup> °C |
| <b>Time within 5°C of actual peak Temperature (<math>t_p</math>)</b>   |                                    | 20 - 40 seconds         |
| <b>Ramp-down Rate</b>  |                                    | 5°C/second max          |
| <b>Time 25°C to peak Temperature (<math>T_p</math>)</b>                |                                    | 8 minutes Max.          |
| <b>Do not exceed</b>   |                                    | 280°C                   |



### Physical Specifications

|                        |   |
|------------------------|---|
| <b>Terminal Finish</b> | 100% Matte Tin-plated   |
| <b>Body Material</b>   | UL recognized epoxy meeting flammability classification 94V-0 |
| <b>Lead Material</b>   | Copper Alloy  |

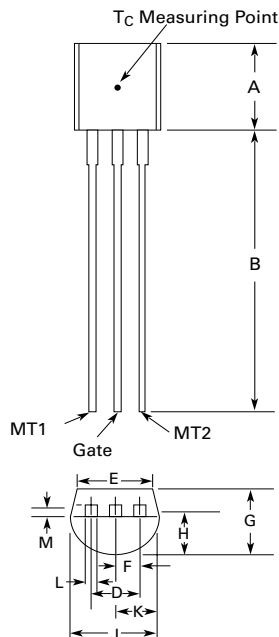
### Design Considerations

Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the device rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including  $dv/dt$ ), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

### Environmental Specifications

| Test                             | Specifications and Conditions  |
|----------------------------------|--|
| <b>AC Blocking</b>               | MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 125°C for 1008 hours |
| <b>Temperature Cycling</b>       | MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell-time        |
| <b>Temperature/Humidity</b>      | EIA / JEDEC, JESD22-A101 1008 hours; 320V - DC: 85°C; 85% rel humidity     |
| <b>High Temp Storage</b>         | MIL-STD-750, M-1031, 1008 hours; 150°C                                     |
| <b>Low-Temp Storage</b>          | 1008 hours; -40°C  |
| <b>Resistance to Solder Heat</b> | MIL-STD-750 Method 2031  |
| <b>Solderability</b>             | ANSI/J-STD-002, category 3, Test A   |
| <b>Lead Bend</b>                 | MIL-STD-750, M-2036 Cond E   |

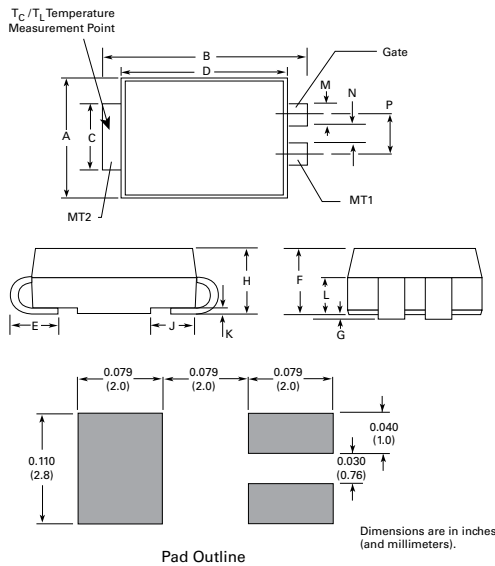
### Dimensions — TO-92 (E Package)



| Dimension | Inches |       | Millimeters |      |
|-----------|--------|-------|-------------|------|
|           | Min    | Max   | Min         | Max  |
| <b>A</b>  | 0.176  | 0.196 | 4.47        | 4.98 |
| <b>B</b>  | 0.500  |       | 12.70       |      |
| <b>D</b>  | 0.095  | 0.105 | 2.41        | 2.67 |
| <b>E</b>  | 0.150  |       | 3.81        |      |
| <b>F</b>  | 0.046  | 0.054 | 1.16        | 1.37 |
| <b>G</b>  | 0.135  | 0.145 | 3.43        | 3.68 |
| <b>H</b>  | 0.088  | 0.096 | 2.23        | 2.44 |
| <b>J</b>  | 0.176  | 0.186 | 4.47        | 4.73 |
| <b>K</b>  | 0.088  | 0.096 | 2.23        | 2.44 |
| <b>L</b>  | 0.013  | 0.019 | 0.33        | 0.48 |
| <b>M</b>  | 0.013  | 0.017 | 0.33        | 0.43 |

All leads insulated from case. Case is electrically nonconductive.

### Dimensions — Compak (C Package)



| Dimension | Inches |       | Millimeters |      |
|-----------|--------|-------|-------------|------|
|           | Min    | Max   | Min         | Max  |
| A         | 0.130  | 0.156 | 3.30        | 3.95 |
| B         | 0.201  | 0.220 | 5.10        | 5.60 |
| C         | 0.077  | 0.087 | 1.95        | 2.20 |
| D         | 0.159  | 0.181 | 4.05        | 4.60 |
| E         | 0.030  | 0.063 | 0.75        | 1.60 |
| F         | 0.075  | 0.096 | 1.90        | 2.45 |
| G         | 0.002  | 0.008 | 0.05        | 0.20 |
| H         | 0.077  | 0.104 | 1.95        | 2.65 |
| J         | 0.043  | 0.053 | 1.09        | 1.35 |
| K         | 0.006  | 0.016 | 0.15        | 0.41 |
| L         | 0.030  | 0.055 | 0.76        | 1.40 |
| M         | 0.022  | 0.028 | 0.56        | 0.71 |
| N         | 0.027  | 0.033 | 0.69        | 0.84 |
| P         | 0.052  | 0.058 | 1.32        | 1.47 |

### Product Selector

| Part Number | Voltage |      | Gate Sensitivity Quadrants |       | Type            | Package |
|-------------|---------|------|----------------------------|-------|-----------------|---------|
|             | 400V    | 600V | I – II – III               | IV    |                 |         |
| LxX8E3      | X       | X    | 3 mA                       | 3 mA  | Sensitive Triac | TO-92   |
| LxX3        | X       | X    | 3 mA                       | 3 mA  | Sensitive Triac | Compak  |
| LxX8E5      | X       | X    | 5 mA                       | 5 mA  | Sensitive Triac | TO-92   |
| LxX5        | X       | X    | 5 mA                       | 5 mA  | Sensitive Triac | Compak  |
| LxX8E6      | X       | X    | 5 mA                       | 10 mA | Sensitive Triac | TO-92   |
| LxX8E8      | X       | X    | 10 mA                      | 20 mA | Sensitive Triac | TO-92   |
| QxX8E3      | X       | X    | 10 mA                      |       | Standard Triac  | TO-92   |
| QxX3        | X       | X    | 10 mA                      |       | Standard Triac  | Compak  |
| QxX8E4      | X       | X    | 25 mA                      |       | Standard Triac  | TO-92   |
| QxX4        | X       | X    | 25 mA                      |       | Standard Triac  | Compak  |

Note: x = voltage

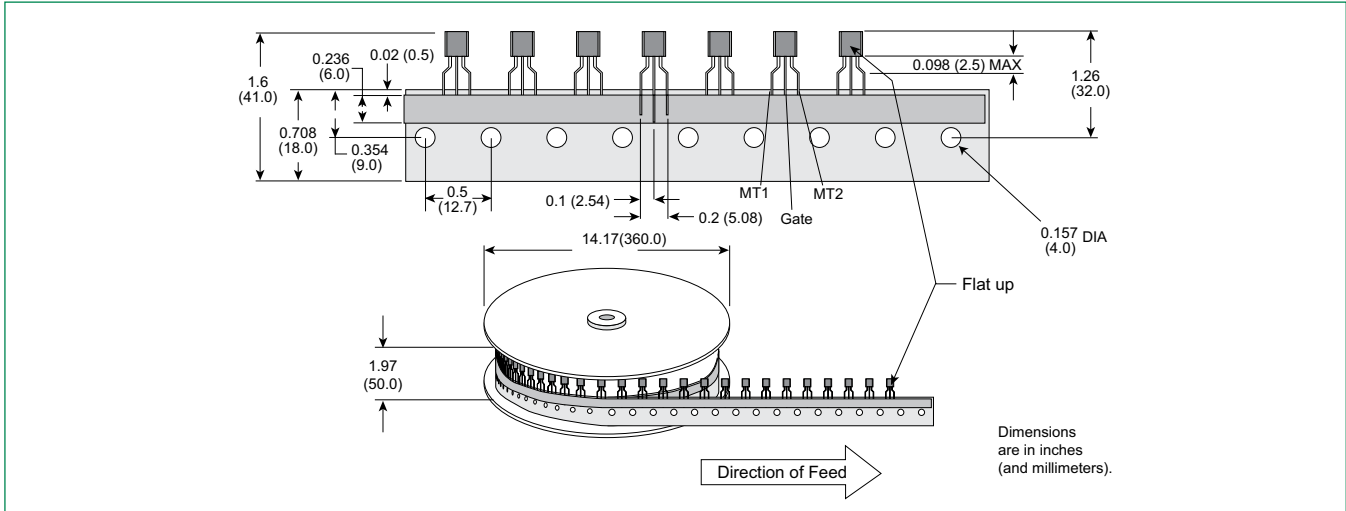
### Packing Options

| Part Number | Marking  | Weight  | Packing Mode     | Base Quantity |
|-------------|----------|---------|------------------|---------------|
| L/QxX8Ey    | L/QxX8Ey | 0.188 g | Bulk             | 2000          |
| L/QxX8EyRP  | L/QxX8Ey | 0.188 g | Reel Pack        | 2000          |
| L/QxX8EyAP  | L/QxX8Ey | 0.188 g | Ammo Pack        | 2000          |
| L/QxXyRP    | L/QxXy   | 0.081 g | Embossed Carrier | 2500          |

Note: x = voltage, y = sensitivity

### TO-92 (3-lead) Reel Pack (RP) Radial Leaded Specifications

Meets all EIA-468-C Standards



### TO-92 (3-lead) Ammo Pack (AP) Radial Leaded Specifications

Meets all EIA-468-C Standards

